TOSHIBA THYRISTOR SILICON PLANAR TYPE

# SF0R5G43,SF0R5J43

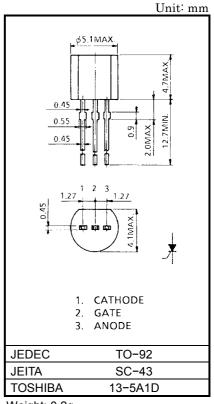
### LOW POWER SWITCHING AND CONTROL APPLICATIONS

• Repetitive Peak Off–State Voltage :  $V_{DRM} = 400,600V$ Repetitive Peak Reverse Voltage :  $V_{RRM} = 400,600V$ • Average On–State Current :  $I_{T}(AV) = 500 \text{mA}$ 

• Plastic Mold Type.

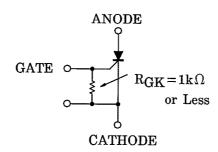
### **MAXIMUM RATINGS**

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Repetitive Peak	SF0R5G43		400		
Off-State Voltage and Repetitive Peak Reverse Voltage $(R_{GK} = 1k\Omega)$	SF0R5J43	V <sub>DRM</sub> V <sub>RRM</sub>	600	V	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive < 5ms, $R_{GK} = 1k\Omega$ , $T_j = 0 \sim 110$ °C)	SF0R5G43		500	V	
	SF0R5J43	$V_{RSM}$	720		
Average On-State Current (Half Sine Waveform Tc = 30°C)		I <sub>T (AV)</sub>	500	mA	
R.M.S On-State Current		I <sub>T (RMS)</sub>	800	mA	
Peak One Cycle Surge On-State Current (Non-Repetitive)		I <sub>TSM</sub>	7 (50Hz)	Α	
			8 (60Hz)	^	
I <sup>2</sup> t Limit Value		ı²t	0.25	A <sup>2</sup> s	
Peak Gate Power Dissipation		$P_{GM}$	1	W	
Average Gate Power Dissipation		P <sub>G (AV)</sub>	0.01	W	
Peak Forward Gate Voltage		$V_{FGM}$	8	V	
Peak Reverse Gate Voltage		$V_{RGM}$	-5	V	
Peak Forward Gate Current		I <sub>GM</sub>	500	mA	
Junction Temperature		Tj	-65~125	°C	
Storage Temperature Ra	ange	T <sub>stg</sub>	-65~125	°C	



Weight: 0.2g

Note: Should be used with gate resistance as follows.

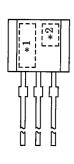




## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

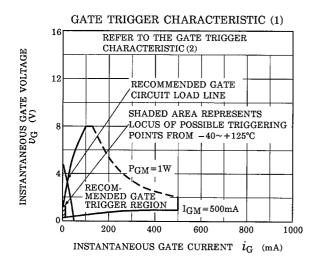
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I <sub>DRM</sub> I <sub>RRM</sub>	$V_{DRM} = V_{RRM} = Rated,$ $R_{GK} = 1k\Omega, T_j = 125^{\circ}C$	_	_	50	μΑ
Peak On-State Voltage	$V_{TM}$	I <sub>TM</sub> = 1A	_	_	1.5	V
Gate Trigger Voltage	V <sub>GT</sub>	$V_D = 6V$ , $R_I = 100Ω$ , $R_{GK} = 1kΩ$	_	_	8.0	V
Gate Trigger Current	I <sub>GT</sub>	1 VD - 0V, NL - 10052, NGK - 1852	_	_	200	μA
Gate Non-Trigger Voltage	$V_{GD}$	$V_D$ = Rated, R <sub>GK</sub> = 1kΩ, T <sub>a</sub> = 125°C	0.2	_	_	V
Holding Current	lΗ	$R_L = 100\Omega$ , $R_{GK} = 1k\Omega$	_	_	5	mA
Thermal Resistance	R <sub>th (j-c)</sub>	Junction to Case —		_	125	°C / W
	R <sub>th (j−a)</sub>	Junction to Ambient	_	_	230	C / VV

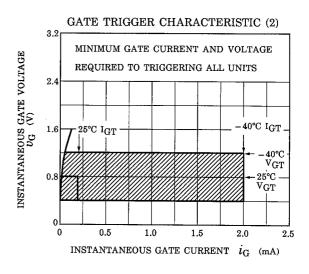
### **MARKING**

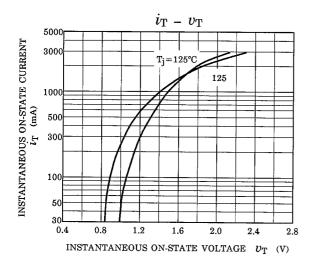


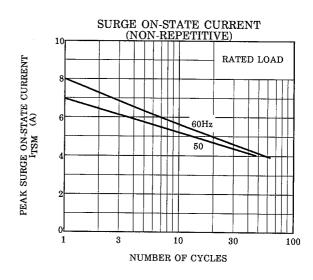
NUMBER	SYM	MARK	
*1	TYPE	SF0R5G43	F0R5G
		SF0R5J43	F0R5J
*2	Lot Number  Month (Starting from Alphabet A)  Year (Last Decimal Digit of the Current Year)		Example 8A: January 1998 8B: February 1998 8L: December 1998

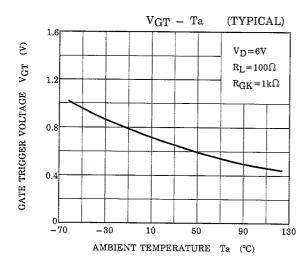
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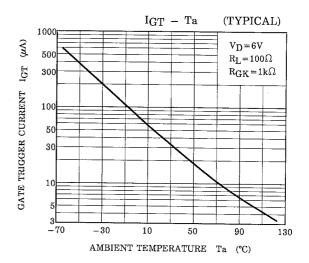


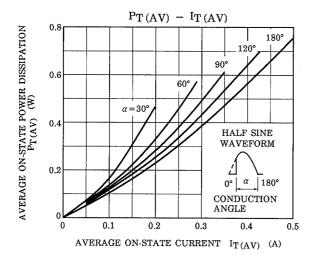


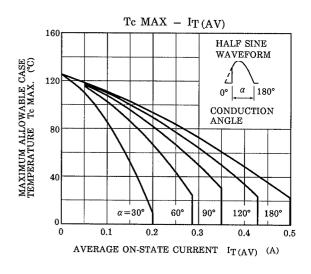


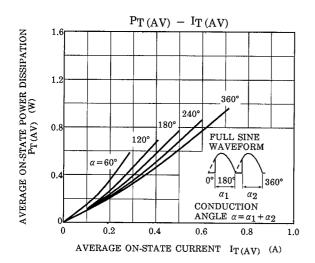


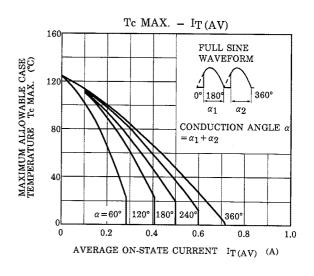


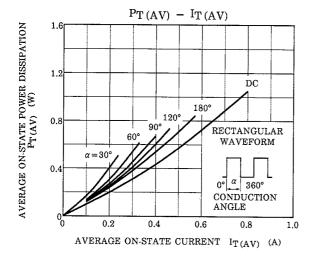


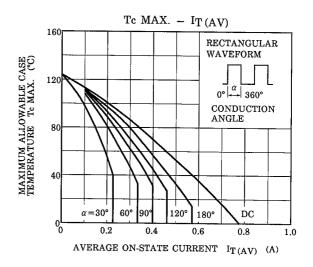


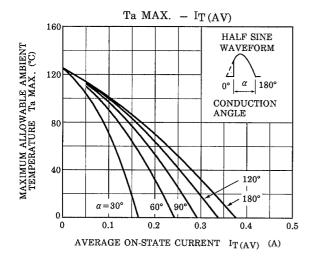


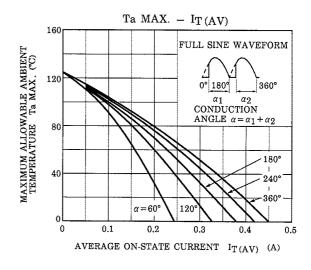


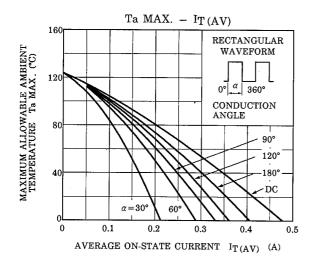


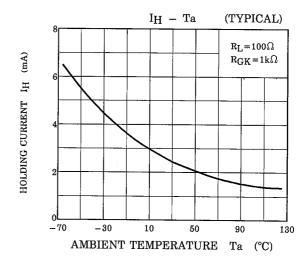


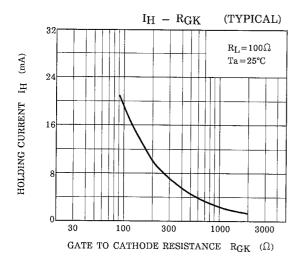


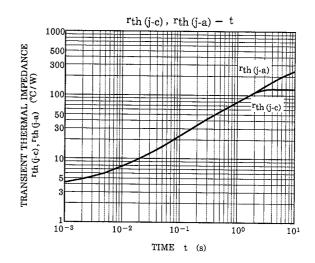












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